# **Complementary Silicon Plastic Power Transistor**

# **DPAK-3 for Surface Mount Applications**

Designed for low voltage, low-power, high-gain audio amplifier applications.

#### **Features**

• Collector-Emitter Sustaining Voltage -

 $V_{CEO(sus)}$  = 100 Vdc (Min) @  $I_C$ = 10 mAdc

• High DC Current Gain -

 $h_{FE} = 40 \text{ (Min)} @ I_{C}$ = 200 mAdc = 15 (Min) @ I\_{C} = 1.0 Adc

- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Low Collector-Emitter Saturation Voltage -

 $V_{CE(sat)} = 0.3 \text{ Vdc (Max)} @ I_{C}$ = 500 mAdc = 0.6 Vdc (Max) @  $I_{C}$  = 1.0 Adc

• High Current-Gain - Bandwidth Product -

 $f_T = 40 \text{ MHz (Min)} @ I_C$ = 100 mAdc

Annular Construction for Low Leakage –

 $I_{CBO} = 100 \text{ nAdc}$  @ Rated  $V_{CB}$ 

- Epoxy Meets UL 94 V-0 @ 0.125 in
- ESD Ratings:
  - Human Body Model, 3B > 8000 V
  - Machine Model, C > 400 V
- NJV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These are Pb-Free Packages\*



## ON Semiconductor®

http://onsemi.com

# 4.0 A, 100 V, 12.5 W POWER TRANSISTOR

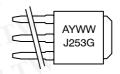




IPAK CASE 369D STYLE 1

DPAK-3 CASE 369C STYLE 1

#### **MARKING DIAGRAMS**





DPAK

IPAK

= Assembly Location

Y = Year

WW = Work Week

C = 4 or 5

G = Pb-Free Package

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

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<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CB</sub>	100	Vdc
Collector-Emitter Voltage	V <sub>CEO</sub>	100	Vdc
Emitter-Base Voltage	V <sub>EB</sub>	7.0	Vdc
Collector Current Continuous Peak	Ic	4.0 8.0	Adc
Base Current	I <sub>B</sub>	1.0	Adc
Total Device Dissipation  @ T <sub>C</sub> = 25°C  Derate above 25°C	P <sub>D</sub>	12.5 0.1	W W/°C
Total Device Dissipation  @ T <sub>A</sub> = 25°C (Note 2)  Derate above 25°C	P <sub>D</sub>	1.4 0.011	W W/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

# THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance Junction-to-Case Junction-to-Ambient (Note 2)	$R_{ heta JC} \ R_{ heta JA}$	10 89.3	°C/W

<sup>2.</sup> When surface mounted on minimum pad sizes recommended.

#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS		Gymbol IIIII			
Collector–Emitter Sustaining Voltage (Note 3) (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0)	V <sub>CEO(sus)</sub>	100		Vdc	
Collector Cutoff Current $(V_{CB} = 100 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 100 \text{ Vdc}, I_E = 0, T_J = 125^{\circ}\text{C})$	Ісво	N :	100 100	nAdc μAdc	
Emitter Cutoff Current (V <sub>BE</sub> = 7.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	W	100	nAdc	
DC Current Gain (Note 3) $ (I_C = 200 \text{ mAdc}, V_{CE} = 1.0 \text{ Vdc}) $ $ (I_C = 1.0 \text{ Adc}, V_{CE} = 1.0 \text{ Vdc}) $	h <sub>FE</sub>	40 15	180 -	W	
Collector–Emitter Saturation Voltage (Note 3) ( $I_C = 500 \text{ mAdc}$ , $I_B = 50 \text{ mAdc}$ ) ( $I_C = 1.0 \text{ Adc}$ , $I_B = 100 \text{ mAdc}$ )	V <sub>CE(sat)</sub>	1.7	0.3 0.6	Vdc	
Base–Emitter Saturation Voltage (Note 3) $(I_C = 2.0 \text{ Adc}, I_B = 200 \text{ mAdc})$	V <sub>BE(sat)</sub>	M-T	1.8	Vdc	
Base-Emitter On Voltage (Note 3) (I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 1.0 Vdc)	V <sub>BE(on)</sub>	1-1-1	1.5	Vdc	
DYNAMIC CHARACTERISTICS					
Current-Gain - Bandwidth Product (Note 4) (I <sub>C</sub> = 100 mAdc, V <sub>CE</sub> = 10 Vdc, f <sub>test</sub> = 10 MHz)	ft	40		MHz	
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 0.1 MHz)	C <sub>ob</sub>	$CO_{J_j}$	50	pF	

<sup>3.</sup> Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\approx$  2%.

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<sup>1.</sup> When surface mounted on minimum pad sizes recommended

<sup>4.</sup>  $f_T = |h_{FE}| \cdot f_{test}$ 

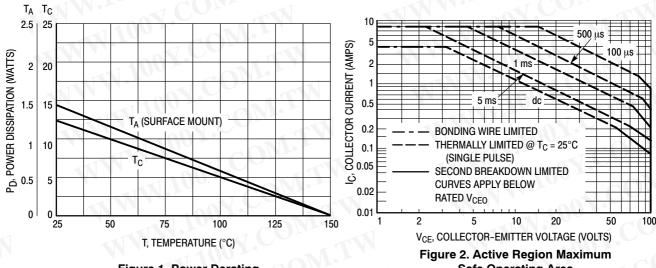


Figure 1. Power Derating

Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate I<sub>C</sub> - V<sub>CE</sub> limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 2 is based on  $T_{J(pk)} = 150$ °C;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \le 150$  °C.  $T_{J(pk)}$  may be calculated from the data in Figure 3. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

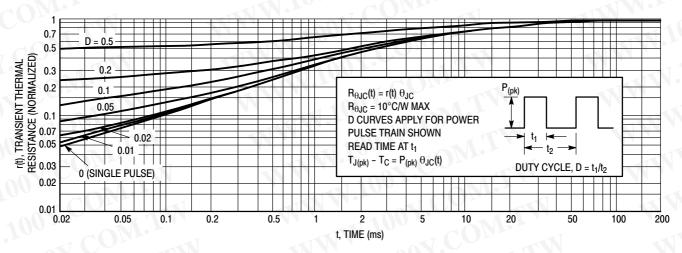


Figure 3. Thermal Response

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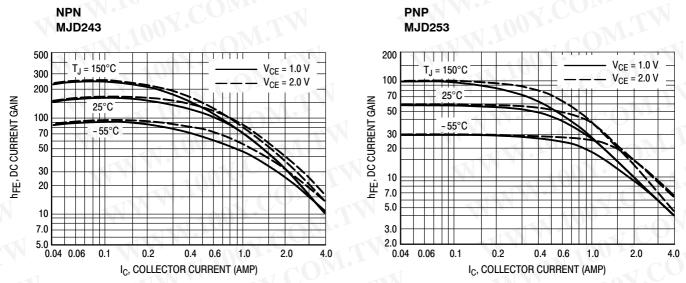


Figure 4. DC Current Gain

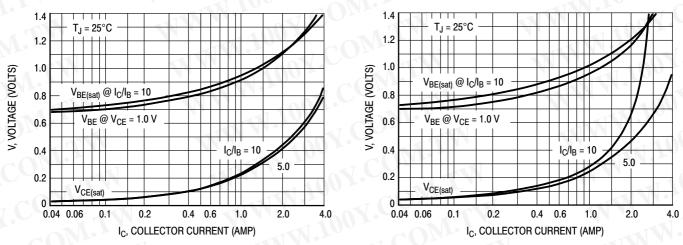
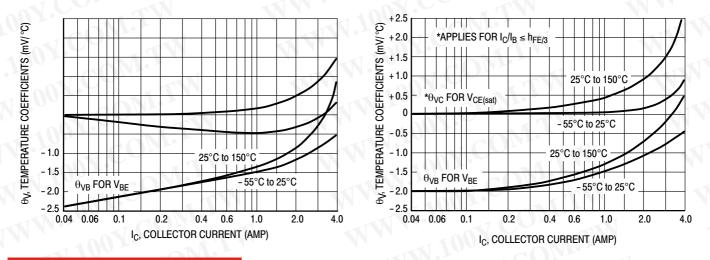
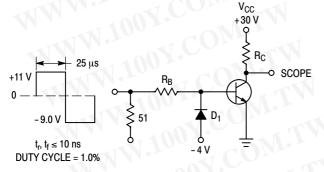


Figure 5. "On" Voltages



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Figure 6. Temperature Coefficients



 $R_B$  and  $R_C$  VARIED TO OBTAIN DESIRED CURRENT LEVELS  $D_1$  MUST BE FAST RECOVERY TYPE, e.g.: 1N5825 USED ABOVE  $I_B\approx 100$  mA MSD6100 USED BELOW  $I_B\approx 100$  mA FOR PNP TEST CIRCUIT, REVERSE ALL POLARITIES

500 300 200 100 t, TIME (ns) 50 30 20 V<sub>CC</sub> = 30 V 10  $I_C/I_B = 10$  $T_J = 25^{\circ}C$ 5 NPN MJD243 PNP MJD253 0.01 0.02 0.03 0.05 0.1 0.2 0.3 0.5 3 5 I<sub>C</sub>, COLLECTOR CURRENT (AMPS)

Figure 8. Turn-On Time

Figure 7. Switching Time Test Circuit

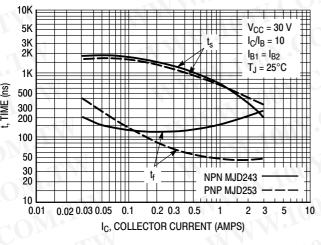


Figure 9. Turn-Off Time

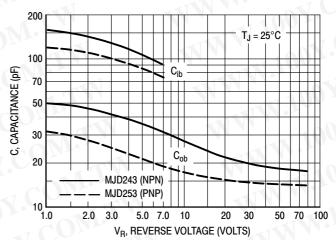


Figure 10. Capacitance

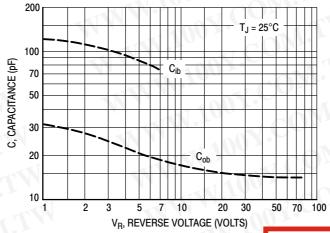


Figure 11. Capacitance

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#### **ORDERING INFORMATION**

Device	Package Type	Package	Shipping <sup>†</sup>
MJD243G	DPAK-3 (Pb-Free)	369C	75 Units / Rail
MJD243T4G	DPAK-3 (Pb-Free)	369C	2,500 / Tape & Reel
NJVMJD243T4G	DPAK-3 (Pb-Free)	369C	2,500 / Tape & Reel
MJD253-1G	IPAK (Pb-Free)	369D	75 Units / Rail
MJD253T4G	DPAK-3 (Pb-Free)	369C	2,500 / Tape & Reel
NJVMJD253T4G	DPAK-3 (Pb-Free)	369C	2,500 / Tape & Reel

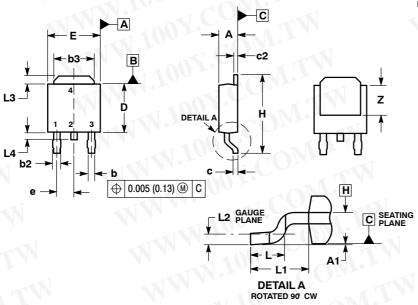
<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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#### PACKAGE DIMENSIONS

#### DPAK-3 CASE 369C-01 ISSUE D



- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

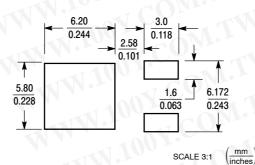
  2. CONTROLLING DIMENSION: INCHES.
- 2. CON HOLLING DIMENSION: INCHES.
  3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.

  4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
- S. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.

  6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

4	INCHES		S MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.086	0.094	2.18	2.38	
A1	0.000	0.005	0.00	0.13	
b	0.025	0.035	0.63	0.89	
b2	0.030	0.045	0.76	1.14	
b3	0.180	0.215	4.57	5.46	
С	0.018	0.024	0.46	0.61	
c2	0.018	0.024	0.46	0.61	
D	0.235	0.245	5.97	6.22	
Е	0.250	0.265	6.35	6.73	
е	0.090	0.090 BSC		BSC	
H	0.370	0.410	9.40	10.41	
L	0.055	0.070	1.40	1.78	
L1	0.108 REF		2.74	REF	
L2	0.020 BSC		0.51	BSC	
L3	0.035	0.050	0.89	1.27	
L4		0.040		1.01	
Z	0.155		3.93	Z 24A	

#### SOLDERING FOOTPRINT



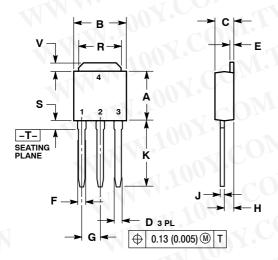
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

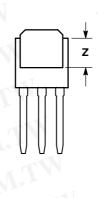
STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

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#### PACKAGE DIMENSIONS

**IPAK** CASE 369D-01 **ISSUE C** 





#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

-	INC	HES	MILLIMETERS	
DIM	MIN	MAX	MIN MAX	
Α	0.235	0.245	5.97	6.35
В	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
Е	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
٧	0.035	0.050	0.89	1.27
7	0.155		3 93	

#### STYLE 1:

PIN 1. BASE

- COLLECTOR EMITTER 2.
- 3.
- COLLECTOR

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